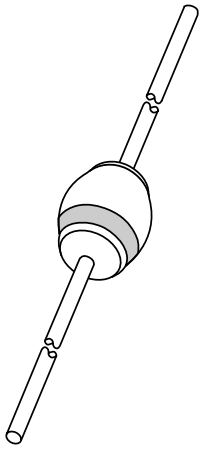
DATA SHEET



BYX10G
Rectifier

Product specification

1996 May 24

Philips
Semiconductors

PHILIPS

Rectifier BYX10G

FEATURES

- Glass passivated
- High maximum operating temperature
- Low leakage current
- Excellent stability
- Available in ammo-pack.

DESCRIPTION

Rugged glass package, using a high temperature alloyed construction. This package is hermetically sealed and fatigue free as coefficients of expansion of all used parts are matched.

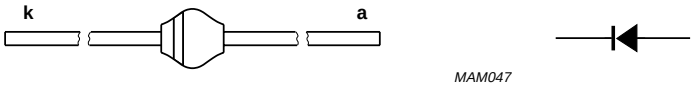


Fig.1 Simplified outline (SOD57) and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{RSM}	non-repetitive peak reverse voltage		–	1600	V
V_{RRM}	repetitive peak reverse voltage		–	1600	V
V_{RWM}	crest working reverse voltage		–	800	V
$I_{F(AV)}$	average forward current	T_{tp} = 50 °C; lead length = 10 mm; averaged over any 20 ms period; see Figs 2 and 4	–	1.2	A
		T_{amb} = 60 °C; PCB mounting (see Fig.9); averaged over any 20 ms period; see Figs 3 and 4	–	0.6	A
I_{FSM}	non-repetitive peak forward current	t = 10 ms half sinewave; $T_j = T_{j\,max}$ prior to surge; $V_R = V_{RWMmax}$	–	25	A
T_{stg}	storage temperature		–65	+175	°C
T_j	junction temperature	see Fig.5	–65	+175	°C

ELECTRICAL CHARACTERISTICS

T_j = 25 °C; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	forward voltage	I_F = 2 A; $T_j = T_{j\ max;}$ see Fig.6	–	–	1.5	V
		I_F = 2 A; see Fig.6	–	–	1.5	V
I_R	reverse current	$V_R = V_{RWMmax}$; see Fig.7	–	–	1	µA
		$V_R = V_{RWMmax}$; T_j = 150 °C; see Fig.7	–	–	200	µA
t_{rr}	reverse recovery time	when switched from I_F = 0.5 A to I_R = 1 A; measured at I_R = 0.25 A; see Fig.10	–	3	–	µs
C_d	diode capacitance	V_R = 0 V; f = 1 MHz; see Fig.8	–	30	–	pF

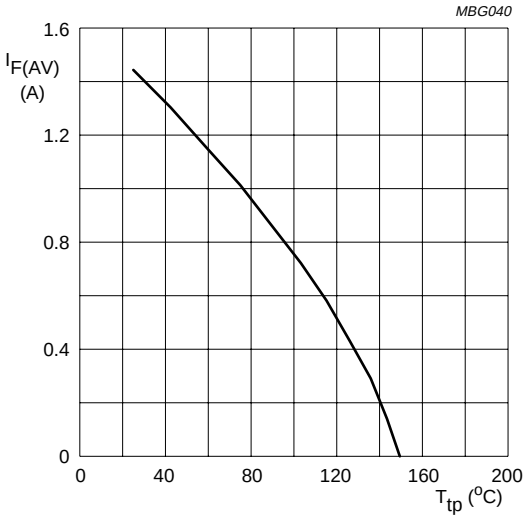
THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j\text{-}tp}$	thermal resistance from junction to tie-point	lead length = 10 mm	46	K/W
$R_{th\ j\text{-}a}$	thermal resistance from junction to ambient	note 1	100	K/W

Note

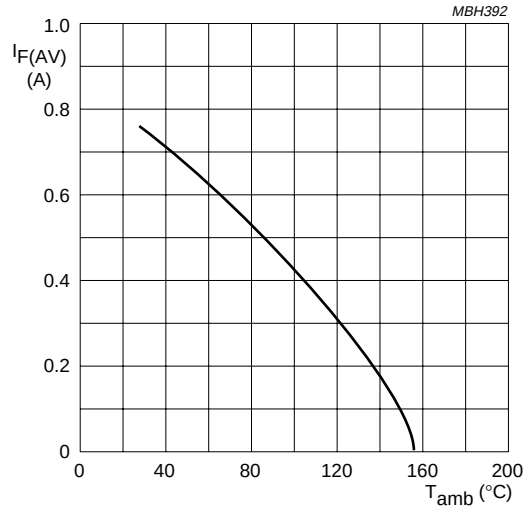
1. Device mounted on epoxy-glass printed-circuit board, 1.5 mm thick; thickness of copper ≥40 µm, see Fig.9. For more information please refer to the *"General Part of associated Handbook"*.

GRAPHICAL DATA



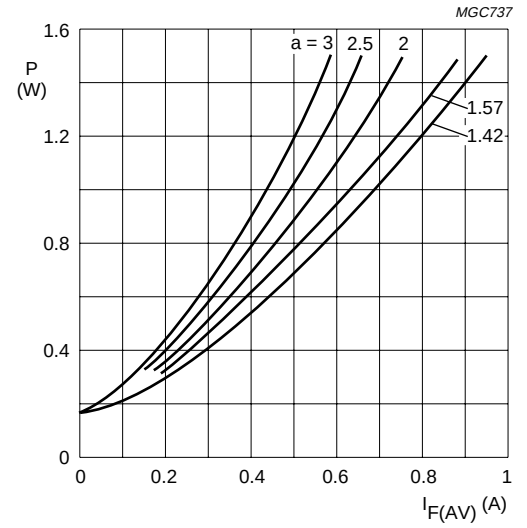
a = 1.57; $V_R = V_{RWMmax}$; δ = 0.5.
Lead length 10 mm.

Fig.2 Maximum permissible average forward current as a function of tie-point temperature (including losses due to reverse leakage).



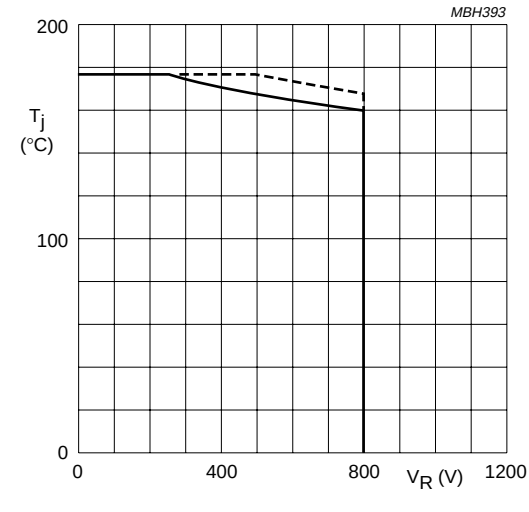
a = 1.57; $V_R = V_{RWMmax}$; δ = 0.5.
Device mounted as shown in Fig.9.

Fig.3 Maximum permissible average forward current as a function of ambient temperature (including losses due to reverse leakage).



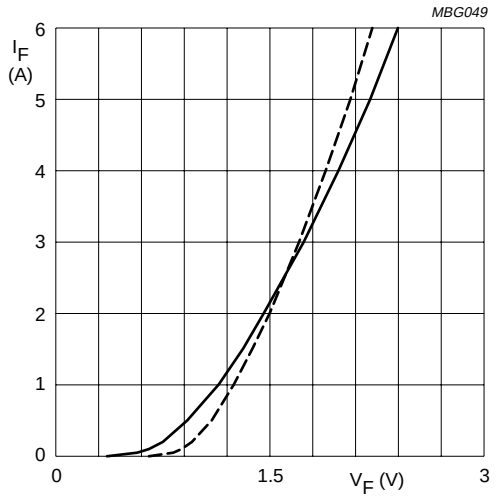
a = $I_{F(RMS)}/I_{F(AV)}$; $V_R = V_{RWMmax}$; δ = 0.5.

Fig.4 Maximum steady state power dissipation (forward plus leakage current losses, excluding switching losses) as a function of average forward current.



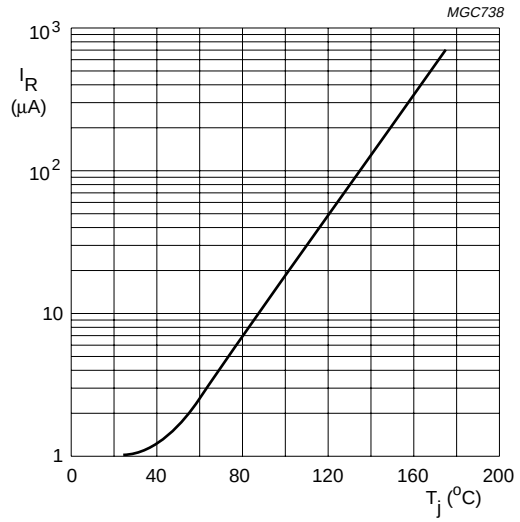
Solid line = V_R.
Dotted line = V_{RWM}; δ = 0.5.

Fig.5 Maximum permissible junction temperature as a function of reverse voltage.



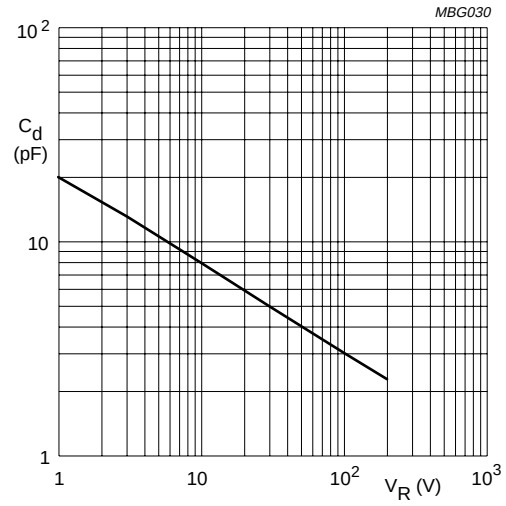
Solid line: T_j = 25 °C.
Dotted line: T_j = 175 °C.

Fig.6 Forward current as a function of forward voltage; maximum values.



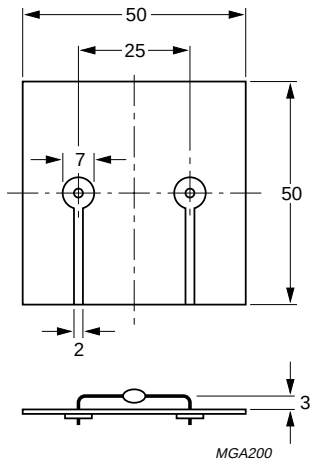
$V_R = V_{RWMmax}$.

Fig.7 Reverse current as a function of junction temperature; maximum values.



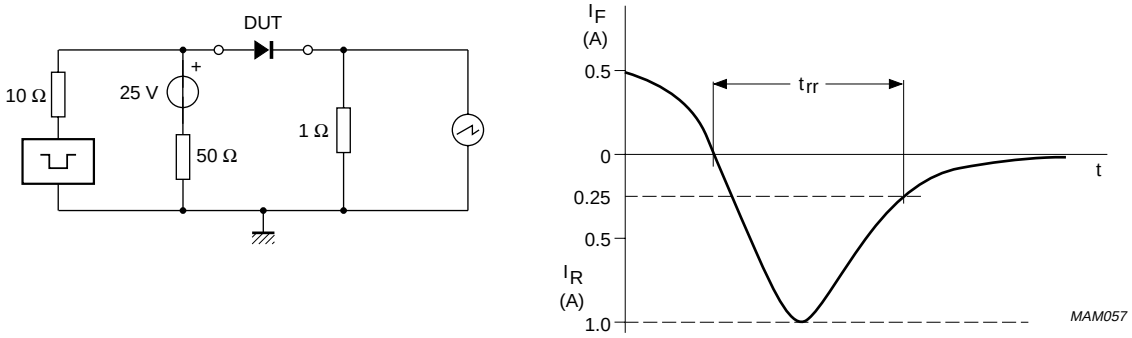
f = 1 MHz; T_j = 25 °C.

Fig.8 Diode capacitance as a function of reverse voltage; typical values.



Dimensions in mm.

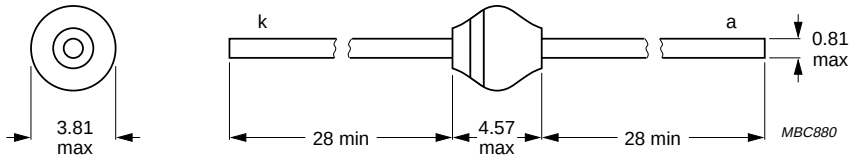
Fig.9 Device mounted on a printed-circuit board.



Input impedance oscilloscope: 1 MΩ, 22 pF; $t_r \leq 7$ ns.
Source impedance: 50 Ω; $t_r \leq 15$ ns.

Fig.10 Test circuit and reverse recovery time waveform and definition.

PACKAGE OUTLINE



Dimensions in mm.

Fig.11 SOD57.

DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.